

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

Product Specification

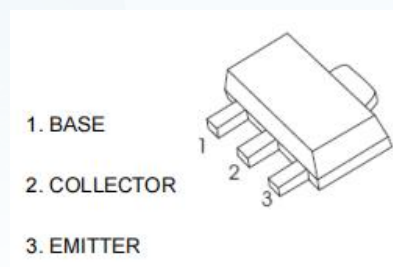
▶ Domestic	Part Number	PBSS5540X
▶ Overseas	Part Number	PBSS5540X
▶ Equivalent	Part Number	PBSS5540X

EV is the abbreviation of name EVVO

SOT-89 Bipolar Transistor 双极型三极管
■Features 特点

PNP Low Saturation Voltage 低饱和压降

MARKING:P56


■Absolute Maximum Ratings 最大额定值

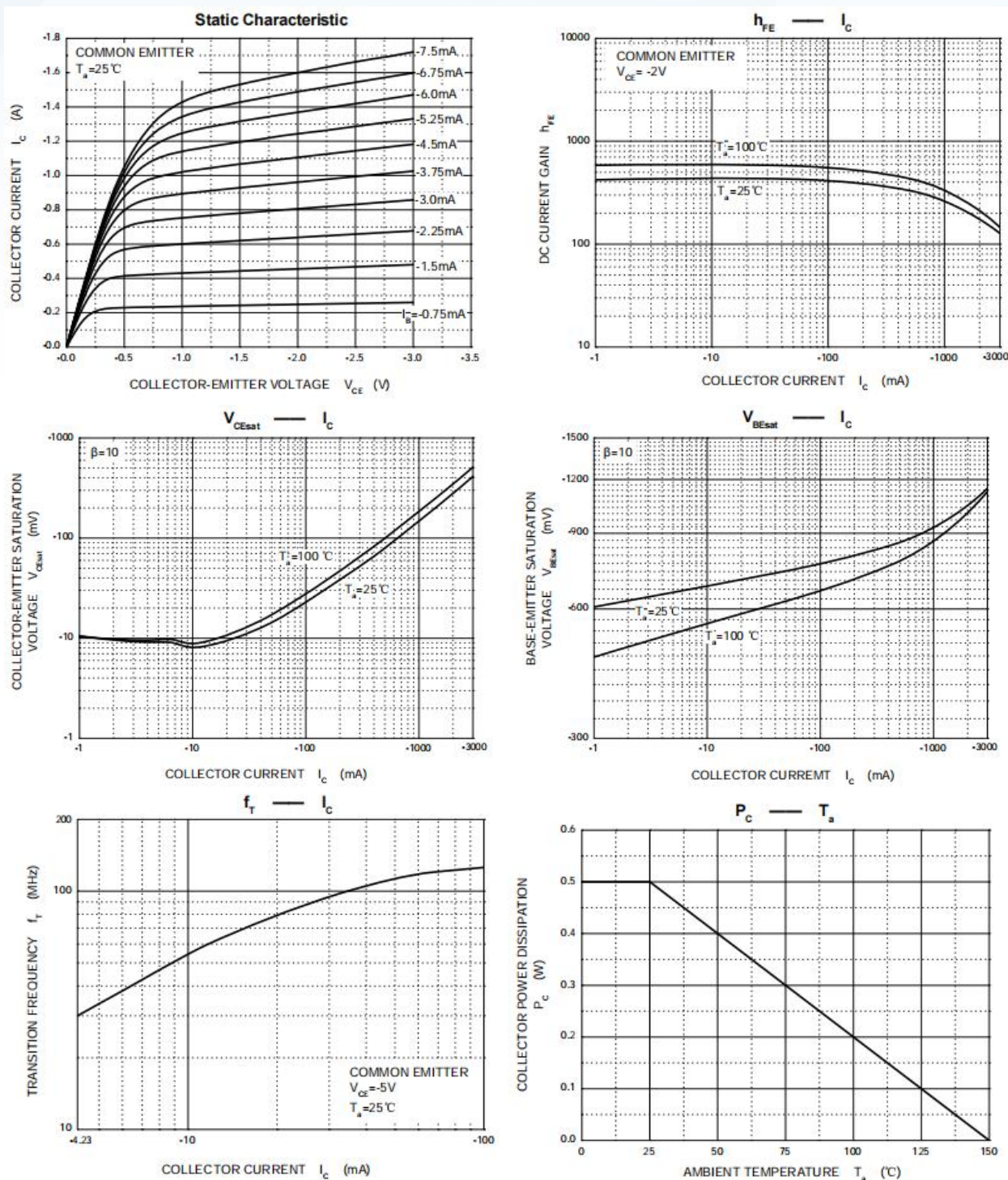
Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
Collector-Base Voltage 集电极基极电压	V_{CBO}	-40	V
Collector-Emitter Voltage 集电极发射极电压	V_{CEO}	-30	V
Emitter-Base Voltage 发射极基极电压	V_{EBO}	-6	V
Collector Current 集电极电流	I_C	-3000	mA
Power dissipation 耗散功率	$P_C(T_a=25^{\circ}\text{C})$	500	mW
Thermal Resistance Junction-Ambient 热阻	$R_{\theta JA}$	250	$^{\circ}\text{C}/\text{W}$
Junction and Storage Temperature 结温和储藏温度	T_J, T_{stg}	-55to+150 $^{\circ}\text{C}$	

■Electrical Characteristics 电特性

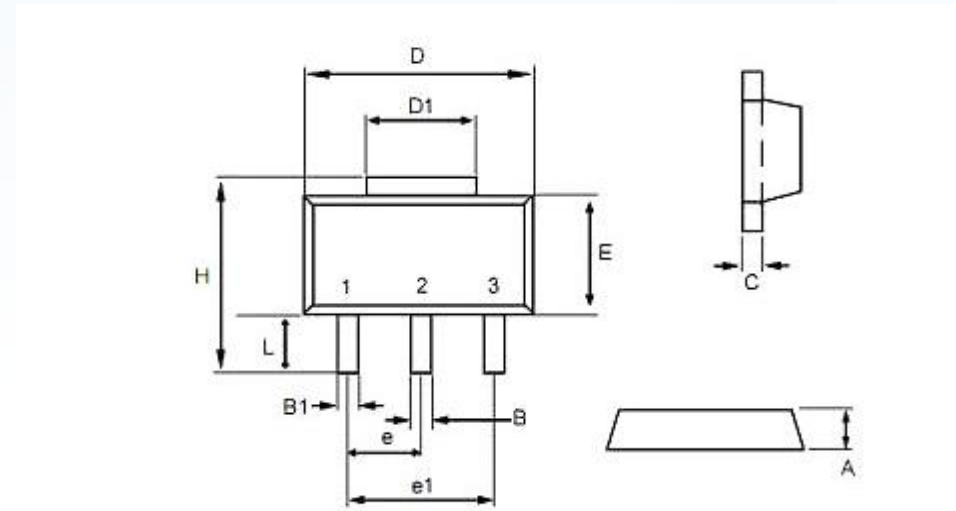
(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Type 典型值	Max 最大值	Unit 单位
Collector-Base Breakdown Voltage 集电极基极击穿电压($I_C = -100\mu A$, $I_E = 0$)	BV_{CBO}	-40	—	—	V
Collector-Emitter Breakdown Voltage 集电极发射极击穿电压($I_C = -10mA$, $I_B = 0$)	BV_{CEO}	-30	—	—	V
Emitter-Base Breakdown Voltage 发射极基极击穿电压($I_E = -100\mu A$, $I_C = 0$)	BV_{EBO}	-6	—	—	V
Collector-Base Leakage Current 集电极基极漏电流($V_{CB} = -40V$, $I_E = 0$)	I_{CBO}	—	—	-1	μA
Collector-Emitter Leakage Current 集电极发射极漏电流($V_{CE} = -30V$, $I_B = 0$)	I_{CEO}	—	—	-10	μA
Emitter-Base Leakage Current 发射极基极漏电流($V_{EB} = -6V$, $I_C = 0$)	I_{EBO}	—	—	-1	μA
DC Current Gain 直流电流增益($V_{CE} = -2V$, $I_C = -1000mA$)	H_{FE}	160	—	320	
Collector-Emitter Saturation Voltage 集电极发射极饱和压降($I_C = -2A$, $I_B = -0.2A$)	$V_{CE(sat)}$	—	—	-0.5	V
Base-Emitter Saturation Voltage 基极发射极饱和压降($I_C = -2A$, $I_B = -0.2A$)	$V_{BE(sat)}$	—	—	-1.5	V
Transition Frequency 特征频率($V_{CE} = -5V$, $I_C = -100mA$)	f_T	—	80	—	MHz
Output Capacitance 输出电容($V_{CB} = -10V$, $I_E = 0$, $f = 1MHz$)	C_{ob}	—	35	—	pF

■ Typical Characteristic Curve 典型特性曲线



■Dimension 外形封装尺寸



Dim	min	max
A	1.40	1.60
B	0.40	0.56
B1	0.35	0.48
C	0.35	0.44
D	4.40	4.60
D1	1.35	1.83
e	1.50 BSC	
e1	3.00 BSC	
E	2.29	2.60
H	3.75	4.25
L	0.80	1.20

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